Product data sheet

1. General description

Ultrafast power diode in a SOD59 (2-lead TO-220AC) plastic package.

2. Features and benefits

- Fast switching
- Low leakage current
- Low forward voltage drop
- Low thermal resistance
- Soft recovery characteristic

3. Applications

- · High frequency switched-mode power supplies
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-------------------------|---------------------------------|--|--|-----|-----|-----|------|
| V _{RRM} | repetitive peak reverse voltage | | | - | - | 600 | V |
| I _{F(AV)} | average forward current | δ = 0.5 ; T _{mb} ≤ 109 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3 | | - | - | 10 | А |
| Static charact | eristics | | | | | | |
| V _F | forward voltage | I _F = 10 A; T _j = 150 °C; <u>Fig. 6</u> | | - | - | 1.6 | ٧ |
| Dynamic characteristics | | | | | | | |
| t _{rr} | reverse recovery time | $I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$ | | - | 20 | - | ns |





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5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------------------------------|--------------------|----------------|
| 1 | K | cathode | mb | K — A |
| 2 | Α | anode | } | 001aaa020 |
| mb | mb | mounting base; connected to cathode | TO-220AC (SOD59) | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | | | | |
|-------------|----------|--|---------|--|--|--|
| | Name | Description | Version | | | |
| BYV10-600P | TO-220AC | plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC | SOD59 | | | |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| BYV10-600P | BYV10-600P |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|--------------------|---------------------------------|--|-----|-----|------|
| V_{RRM} | repetitive peak reverse voltage | | - | 600 | V |
| V_{RWM} | crest working reverse voltage | | - | 600 | V |
| V _R | reverse voltage | DC | - | 600 | V |
| I _{F(AV)} | average forward current | δ = 0.5 ; T _{mb} ≤ 109 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3 | - | 10 | А |
| I _{FRM} | repetitive peak forward current | δ = 0.5 ; t _p = 25 µs; T _{mb} ≤ 109 °C; square-wave pulse | - | 20 | А |

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| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------------------|--|-----|-----|------|
| I _{FSM} | non-repetitive peak forward current | t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4 | - | 80 | А |
| | | t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4 | - | 88 | Α |
| T _{stg} | storage temperature | | -65 | 175 | °C |
| Tj | junction temperature | | - | 175 | °C |

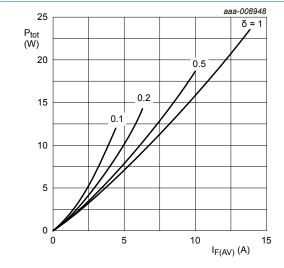


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_{O} &= 1.268 \text{ V}; \text{ R}_{S} = 0.031 \Omega \end{split}$$

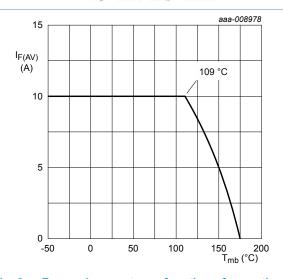


Fig. 3. Forward current as a function of mounting base temperature; maximum values

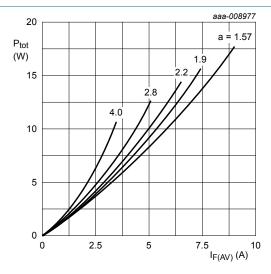


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

a = form factor =
$$I_{F(RMS)}/I_{F(AV)}$$

 $V_O = 1.268 \text{ V}; R_S = 0.031 \Omega$

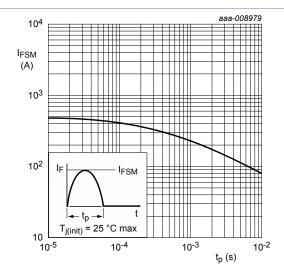


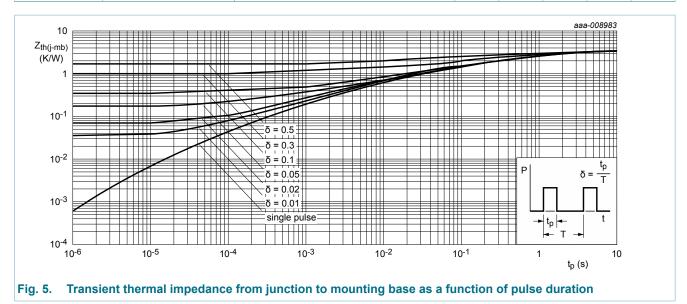
Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

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9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---|-------------|-----|-----|-----|------|
| R _{th(j-mb)} | thermal resistance from junction to mounting base | Fig. 5 | - | - | 3.5 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |



10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|---------------------------------------|---|--|---|-----|-----|-----|------|
| Static characteristics | | | | | | | |
| V _F | forward voltage | I _F = 10 A; T _j = 25 °C; <u>Fig. 6</u> | | - | 1.5 | 2 | V |
| | | I _F = 10 A; T _j = 150 °C; <u>Fig. 6</u> | | - | - | 1.6 | V |
| I _R reverse current | reverse current | V _R = 600 V; T _j = 25 °C | | - | - | 10 | μA |
| | | V _R = 500 V; T _j = 150 °C | | - | - | 250 | μA |
| Dynamic cl | haracteristics | 1 | I | | | | |
| t _{rr} reverse recovery time | $I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$ | | - | 35 | 50 | ns | |
| | | $I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$ | | - | 20 | - | ns |

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------|-----------|--|-----|-----|-----|------|
| | | $I_F = 10 \text{ A}$; $V_R = 200 \text{ V}$; $dI_F/dt = 200 \text{ A}$ / | - | 40 | - | ns |
| | | μs; T _j = 25 °C; <u>Fig. 7</u> | | | | |

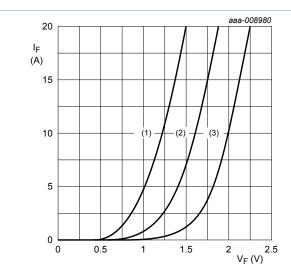


Fig. 6. Forward current as a function of forward voltage

(1) $T_j = 150$ °C; typical values; (2) $T_j = 150$ °C; maximum values; (3) $T_j = 25$ °C; maximum values; $V_Q = 1.268$ V; $R_S = 0.031$ Ω

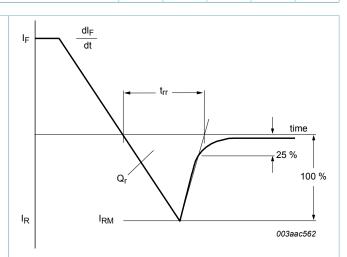
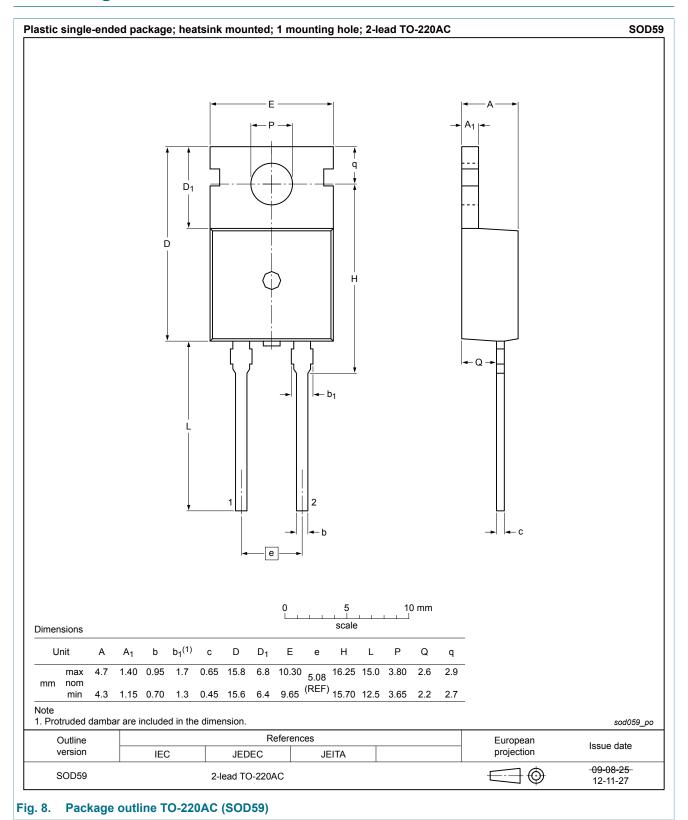


Fig. 7. Reverse recovery definitions; ramp recovery

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11. Package outline



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12. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|--------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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